SENSITRON SEMICONDUCTOR

TECHNICAL DATA DATA SHEET 4519, REV. A

POWER SCHOTTKY RECTIFIER Low Reverse Leakage

Applications:

• Switching Power Supply • Converters • Free-Wheeling Diodes • Polarity Protection Diode

Features:

- Ultra Low Reverse Leakage Current
- Soft Reverse Recovery at Low and High Temperature
- Very Low Forward Voltage Drop
- Low Power Loss, High Efficiency
- High Surge Capacity
- Guard Ring for Enhanced Durability and Long Term Reliability
- Guaranteed Reverse Avalanche Characteristics

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	V _{RWM}	-	45	V
Max. Average Forward	I _{F(AV)}	50% duty cycle, rectangular	60	А
Current		wave form		
Max. Peak One Cycle Non-	I _{FSM}	8.3 ms, half Sine wave	860	A
Repetitive Surge Current		(per leg)		
Non-Repetitive Avalanche	E _{AS}	T _J = 25 °C, I _{AS} = 1.3 A,	27	mJ
Energy		L = 40mH (per leg)		
Repetitive Avalanche	I _{AR}	I_{AS} decay linearly to 0 in 1 μ s	1.3	A
Current		f limited by $T_J max V_A = 1.5 V_R$		
Thermal Resistance	R _{thJC}	Per Package	0.7	°C/W
Max. Junction Temperature	TJ	-	-65 to +175	°C
Max. Storage Temperature	T _{stg}	-	-65 to +175	°C

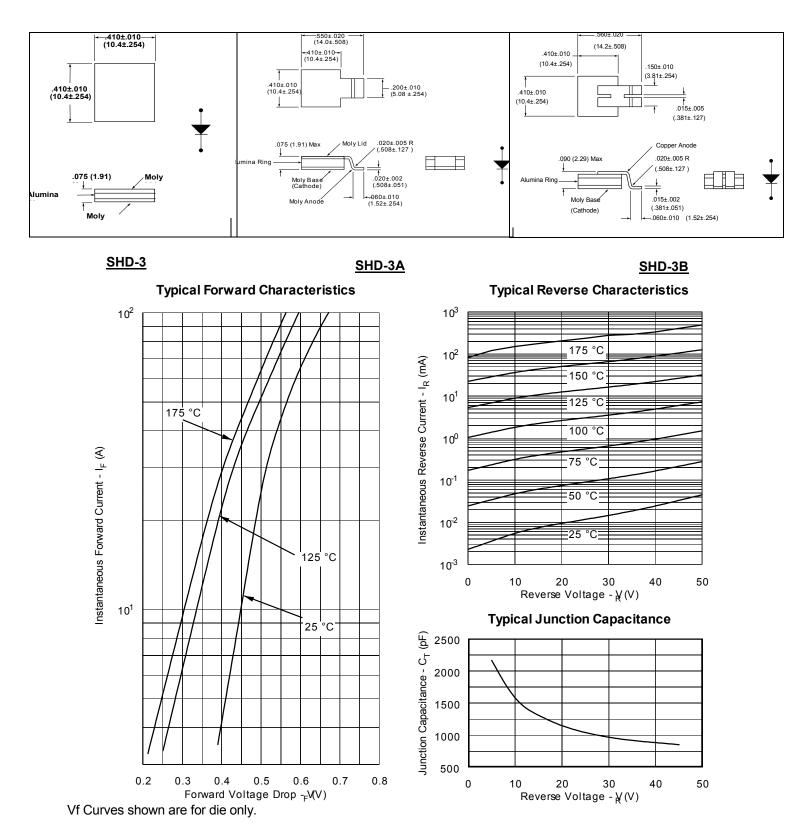
Electrical Characteristics:

Characteristics	Symbol	Condition	Max.	Units
Max. Forward Voltage Drop	V _{F1}	@ 60A, Pulse, $T_J = 25 \text{ °C}$ (per leg) measured at the leads	0.66	V
	V _{F2}	@ 60A, Pulse, T_J = 125 °C (per leg) measured at the leads	0.59	V
Max. Reverse Current	I _{R1}	$@V_R = 45V$, Pulse, T _J = 25 °C (per leg)	1.2	mA
	I _{R2}	@V _R = 45V, Pulse, T _J = 125 °C (per leg)	45	mA
Max. Junction Capacitance	Ст	$@V_R = 5 V, T_C = 25 °C$ $f_{SIG} = 1 MHz,$ $V_{SIG} = 50mV (p-p) (per leg)$	2400	pF

Due to the nature of the 45V Schottky devices, some degradation in t_{rr} performance at high temperatures should be expected, unlike conventional lower voltage Schottkys.

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Mechanical Dimensions: in inches / mm



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